## Octal Bidirectional Transceiver with 3-State Input/Output

# HITACHI

#### Description

The HD74AC245/HD74ACT245 contains eight non-inverting bidirectional buffers with 3-state outputs and is intended for bus-oriented applications. Current sinking capability is 24 mA at both the A and B ports. The Transmit/Receive  $(T/\overline{R})$  input determines the direction of data flow through the bidirectional transceiver. Transmit (active-High) enables data from A ports to B ports; Receive (active-Low) enables data from B ports to A ports. The Output Enable input, when High, disables, both A and B ports by placing them in a High Z condition.

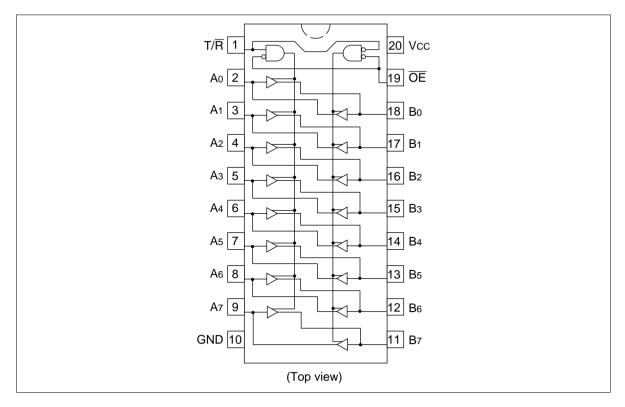
#### Features

- Noninverting Buffers
- Bidirectional Data Path
- A and B Outputs Source/Sink 24 mA
- HD74ACT245 has TTL-Compatible Inputs

#### **Pin Names**



#### **Pin Arrangement**



#### **Truth Tables**

#### Inputs

ŌE	T/R	Outputs	
L	L	Bus B Data to Bus A	
L	Н	Bus A Data to Bus B	
Н	Х	High Z State	

H : High Voltage Level

L : Low Voltage Level

X : Immaterial

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#### DC Characteristics (unless otherwise specified)

Item	Symbol	Max	Unit	Condition
Maximum quiescent supply current	I <sub>cc</sub>	80	μΑ	$V_{IN} = V_{CC}$ or ground, $V_{CC} = 5.5 V$ , Ta = Worst case
Maximum quiescent supply current	I <sub>cc</sub>	8.0	μΑ	$V_{IN} = V_{CC}$ or ground, $V_{CC} = 5.5 \text{ V}$ , Ta = 25°C
Maximum additional I <sub>cc</sub> /input (HD74ACT245)	I <sub>CCT</sub>	1.5	mA	$V_{IN} = V_{CC} - 2.1 \text{ V}, V_{CC} = 5.5 \text{ V},$ Ta = Worst case

#### AC Characteristics: HD74AC245

			Ta = +25°C C <sub>∟</sub> = 50 pF			Ta = −40°C to +85°C C <sub>L</sub> = 50 pF		
ltem	Symbol	V <sub>cc</sub> (V)* <sup>1</sup>	Min	Тур	Max	Min	Max	Unit
Propagation delay	t <sub>PLH</sub>	3.3	1.0	5.0	8.5	1.0	9.0	ns
Data to output		5.0	1.0	3.5	6.5	1.0	7.0	
Propagation delay	t <sub>PHL</sub>	3.3	1.0	5.0	8.5	1.0	9.0	ns
Data to output		5.0	1.0	3.5	6.0	1.0	7.0	
Output enable time	t <sub>PZH</sub>	3.3	1.0	7.0	11.5	1.0	12.5	ns
		5.0	1.0	5.0	8.5	1.0	9.0	
Output enable time	t <sub>PZL</sub>	3.3	1.0	7.5	12.0	1.0	13.5	ns
		5.0	1.0	5.5	9.0	1.0	9.5	
Output disable time	t <sub>PHZ</sub>	3.3	1.0	6.5	12.0	1.0	12.5	ns
		5.0	1.0	5.5	9.0	1.0	10.0	_
Output disable time	t <sub>PLZ</sub>	3.3	1.0	7.0	11.5	1.0	13.0	ns
		5.0	1.0	5.5	9.0	1.0	10.0	

Note: 1. Voltage Range 3.3 is  $3.3 \text{ V} \pm 0.3 \text{ V}$ Voltage Range 5.0 is  $5.0 \text{ V} \pm 0.5 \text{ V}$ 

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#### AC Characteristics: HD74ACT245

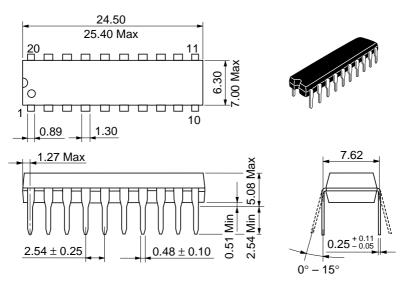
			Ta = +25°C C <sub>∟</sub> = 50 pF			Ta = −40°C to +85°C C <sub>∟</sub> = 50 pF		
Item	Symbol	V <sub>cc</sub> (V)* <sup>1</sup>	Min	Тур	Max	Min	Max	Unit
Propagation delay Data to output	t <sub>PLH</sub>	5.0	1.0	4.0	7.5	1.0	8.0	ns
Propagation delay Data to output	t <sub>PHL</sub>	5.0	1.0	4.0	8.0	1.0	9.0	ns
Output enable time	t <sub>PZH</sub>	5.0	1.0	5.0	10.0	1.0	11.0	ns
Output enable time	t <sub>PZL</sub>	5.0	1.0	5.5	10.0	1.0	12.0	ns
Output disable time	t <sub>PHZ</sub>	5.0	1.0	5.5	10.0	1.0	11.0	ns
Output disable time	t <sub>PLZ</sub>	5.0	1.0	5.0	10.0	1.0	11.0	ns

Note: 1. Voltage Range 5.0 is 5.0 V  $\pm$  0.5 V

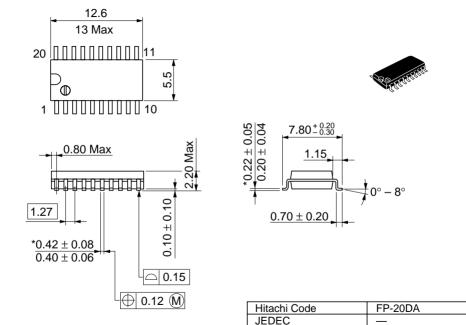
#### Capacitance

ltem	Symbol	Тур	Unit	Condition
Input capacitance	C <sub>IN</sub>	4.5	pF	$V_{cc} = 5.5 V$
Input/output capacitance	C <sub>I/O</sub>	15.0	pF	$V_{cc} = 5.5 V$
Power dissipation capacitance	$C_{PD}$	45.0	pF	$V_{cc} = 5.0 V$

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Hitachi Code	DP-20N
JEDEC	—
EIAJ	Conforms
Weight (reference value	) 1.26 g



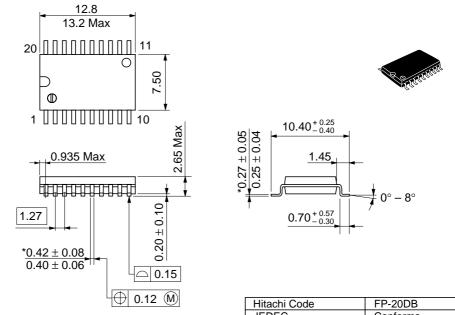
EIAJ

Weight (reference value)

Conforms

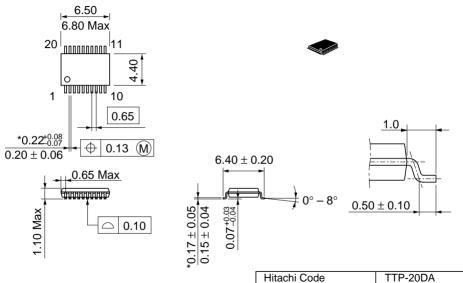
0.31 g

\*Dimension including the plating thickness Base material dimension



\*Dimension including the plating thickness Base material dimension

Hitachi Code	FP-20DB
JEDEC	Conforms
EIAJ	_
Weight (reference value)	0.52 g



\*Dimension including the plating thickness Base material dimension

Hitachi Code	TTP-20DA
JEDEC	—
EIAJ	_
Weight (reference value)	0.07 g

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Semiconductor & Integrated Circuits. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109 NorthAmerica URL http:semiconductor.hitachi.com/ http://www.hitachi-eu.com/hel/ecg Europe http://www.has.hitachi.com.sg/grp3/sicd/index.htm http://www.hitachi.com.tw/E/Product/SICD\_Frame.htm Asia (Singapore) Asia (Taiwan) Asia (HongKong) http://www.hitachi.com.hk/eng/bo/grp3/index.htm http://www.hitachi.co.jp/Sicd/indx.htm Japan For further information write to: Hitachi Semiconductor Hitachi Europe GmbH Hitachi Asia Pte. Ltd. (America) Inc. Electronic components Group 16 Collyer Quay #20-00 179 East Tasman Drive, Dornacher Stra§e 3 Hitachi Tower San Jose,CA 95134 D-85622 Feldkirchen, Munich Singapore 049318 Tel: <1> (408) 433-1990 Fax: <1>(408) 433-0223 Germany Tel: 535-2100 Tel: <49> (89) 9 9180-0 Fax: 535-1533 Fax: <49> (89) 9 29 30 00

 Fax: <49> (89) 9 29 30 00
 Hita

 Hitachi Europe Ltd.
 Hita

 Electronic Components Group.
 Taip

 Whitebrook Park
 3F,

 Lower Cookham Road
 Tun

 Maidenhead
 Tel:

 Berkshire SL6 8YA, United Kingdom
 Fax

 Tel: <44> (1628) 585000

 Fax: <44> (1628) 778322

Hitachi Asia Ltd. Taipei Branch Office 3F, Hung Kuo Building. No.167, Tun-Hwa North Road, Taipei (105) Tel: <886> (2) 2718-3666 Fax: <886> (2) 2718-8180

HITACHI

Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Tsim Sha Tsui, Kowloon, Hong Kong Tel: <852> (2) 735 9218 Fax: <852> (2) 730 0281 Telex: 40815 HITEC HX

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